

# Optimized Illumination Directions of Single-photon Detectors Integrated with Different Plasmonic Structures

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## IDEA:

- Integration of plasmonic structures (reflectors, NCA, NCDA into SNSPDs)
- Optimization of the geometry and illumination direction
- Optical responses, near-field distribution FEM

Mária Csete  
COMSOL conference Boston, 2012

# Superconducting Nanowire Single Photon Detectors (SNSPD)

## SNSPD

- Application areas
  - ◆ IR photon counting
  - ◆ Quantum cryptography
  - ◆ Ultra-long range communication

### ➤ Standard structure

- ◆ 200 nm boustrophedonic pattern of  
4 nm thick NbN stripes with 50 % fill-factor  
2 nm thick NbNO<sub>x</sub>

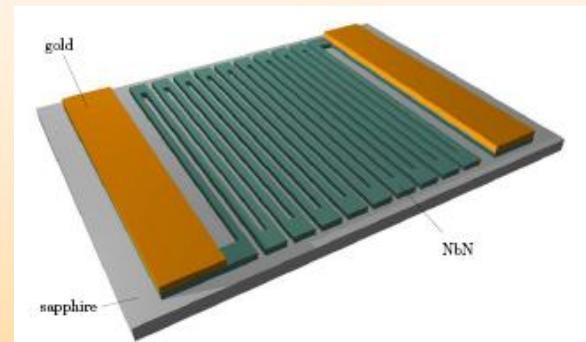
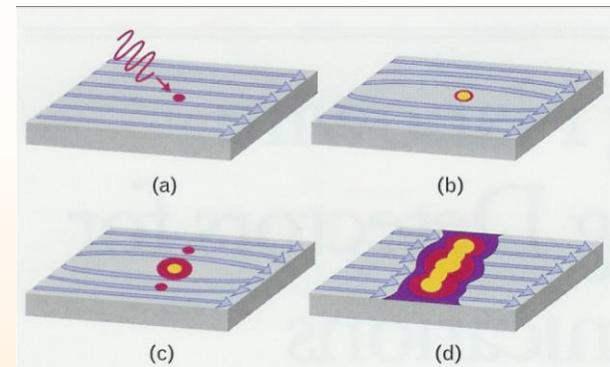
## SNSPD detection efficiency limited

### ➤ Losses

- ◆ Reflection
- ◆ Transmission
- ◆ Absorption by non-active elements

### ➤ Optimization

- ◆ NbN absorptance maximization



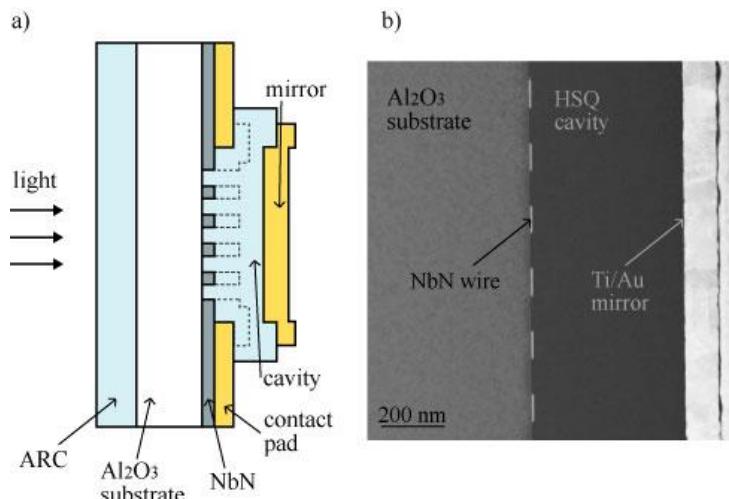
- Detection efficiency  $DE = P_R \cdot A$ 
  - ◆ Optical optimization
    - ◆ Absorptance maximization:  $A$
  - ◆ Electrical optimization
    - ◆ Probability of measurable electronic signal:  $P_R$

Gol'tsman, G. N., Okunev, O., Chulkova, G., Lipatov, A., Semenov, A., Smirnov, K., Voronov, B. M., Dzardanov, A., Williams, C., and Sobolewski, R., „Picosecond superconducting single-photon optical detector” Appl. Phys. Lett. **79(6)** 705-708 (2001).

# First approach: device design optimization

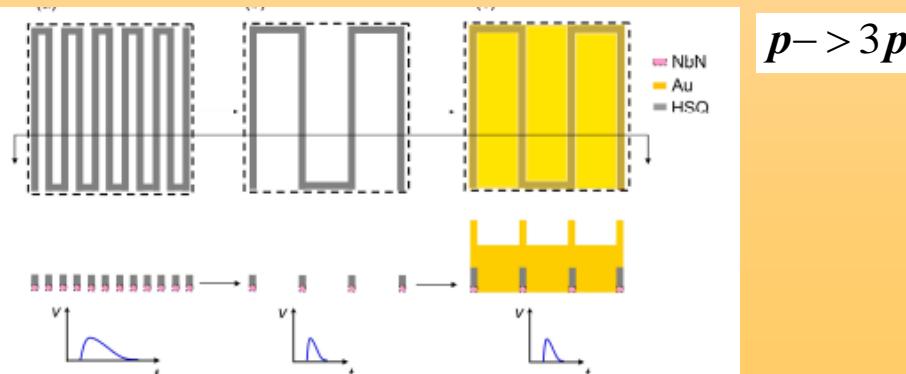
## ► Integrated optical cavity

- ◆ HSQ-filled dielectric cavity
- ◆ Anti-Reflection-Coating: 120 nm Au film
- ◆  $DE=57\%$  at 1550 nm



◆ K.M. Rosfjord et all: Opt. Express Vol. **14/2**, 527-534 (2006)

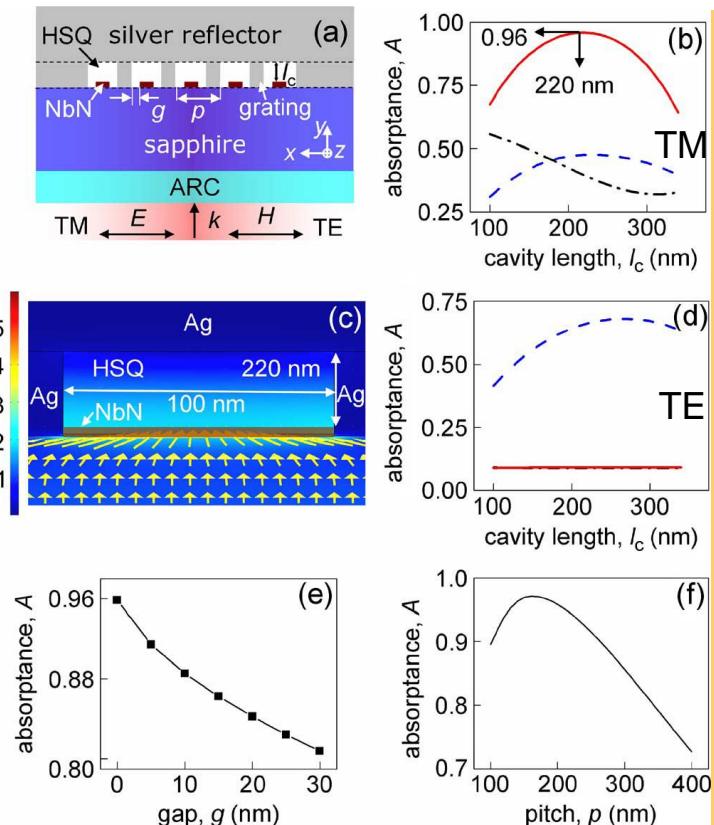
◆ M. Csete et all: Journal of Nanophotonics (2012)



## ► Integrated metal antenna-array

- ◆ Silver antenna:  $DE=96\%$

- ◆  $p_{NbN/Au}=200\text{ nm}$  pitch
- ◆  $l_{HSQ} = 220\text{ nm}$
- ◆ No-gap between the antenna-NbN



◆ X. Hu et all.: IEEE Transactions on Appl. Superc., VOL. **19/3**, 336-340 (2009)

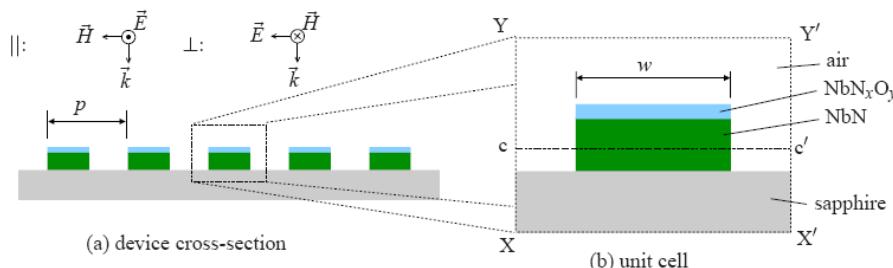
◆ X. Hu et all.: Opt. Express, VOL. **19/1**, 17-31 (2009)

◆ M. Csete et all: Opt. Express, VOL. **20/15**, 17065 (2012)

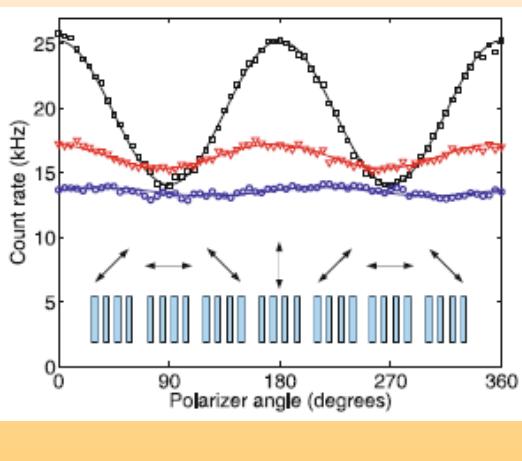
# Second approach: illumination direction optimization

## Effect of E-field oscillation direction

### Variation of the azimuthal angle



◆ V. Anant et al.: Optics Express **16/14**, 2008



◆ E-field oscillation parallel to the NbN wires is advantageous

◆ E. F. C. Driesssen et al.: The European Journal of Applied Physics Vol. **47**, 1071/1-6 (2009)

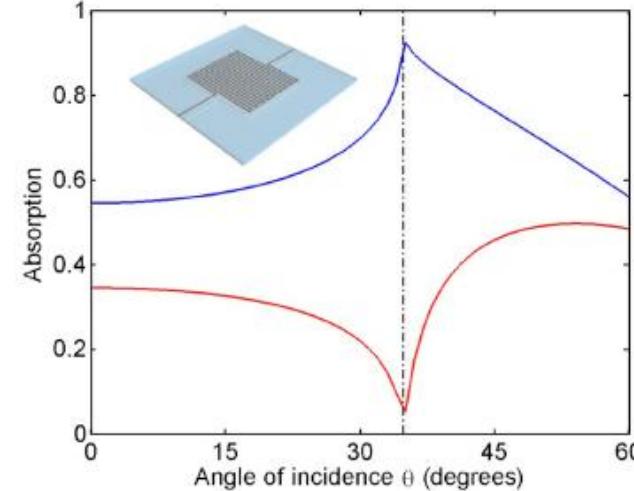
## Effect of tilting

### Variation of the polar angle

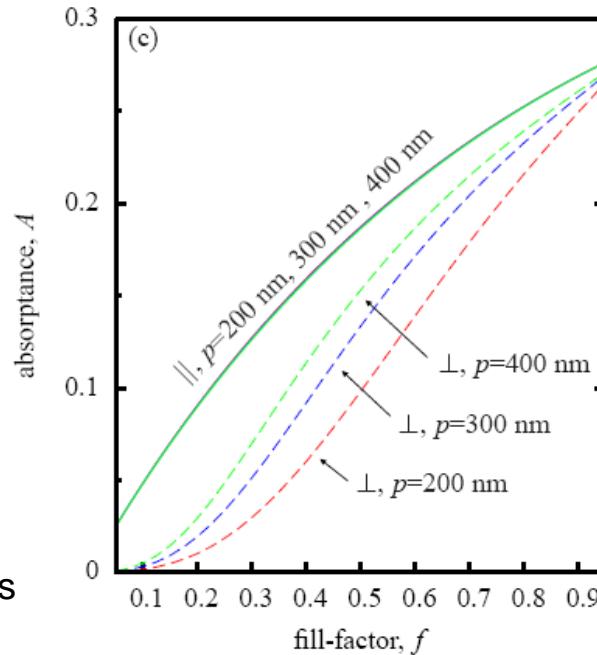
### NbN pattern: lossy thin layer

### Absorption for s-polarized light: 100%

s-polarization: perfect absorptance at TIR



p-polarization: zero absorptance at TIR



◆ E. F. C. Driesssen and M. J. A. de Dood: Applied Physics Letters Vol. **94**, 171109/1-3, 2009  
◆ M. Csete et al.: Appl. Opt. **50(29)** 5949 (2011)  
◆ M. Csete et al.: Journal of Nanophotonics (2012)

# COMSOL 3.5, 4.2: RF module

## Idea:

simultaneous optimization of  
device design + illumination directions

- ◆ p-polarized light, in P/S-orientation
- ◆ off-axes illumination:  $\varphi$  polar angle tuning
- ◆ conical mounting:  $\gamma$  azimuthal angle tuning
- ◆ Absorptance=Sum of the Resistive heating/Total power,
- ◆ Transmittance and Reflectance: Power out-flows at PMLs

## Specification of $\mathbf{H}$ field

$$H_{x\_TM} \cdot \exp(-j(k_x \cdot x + k_y \cdot y + k_z \cdot z))$$

$$H_{y\_TM} \cdot \exp(-j(k_x \cdot x + k_y \cdot y + k_z \cdot z))$$

$$H_{z\_TM} \cdot \exp(-j(k_x \cdot x + k_y \cdot y + k_z \cdot z))$$

## Components of $\mathbf{H}$ vector

$$H_{x\_TM} = H_0 \cdot \cos \gamma$$

$$H_{y\_TM} = -H_0 \cdot \sin \gamma$$

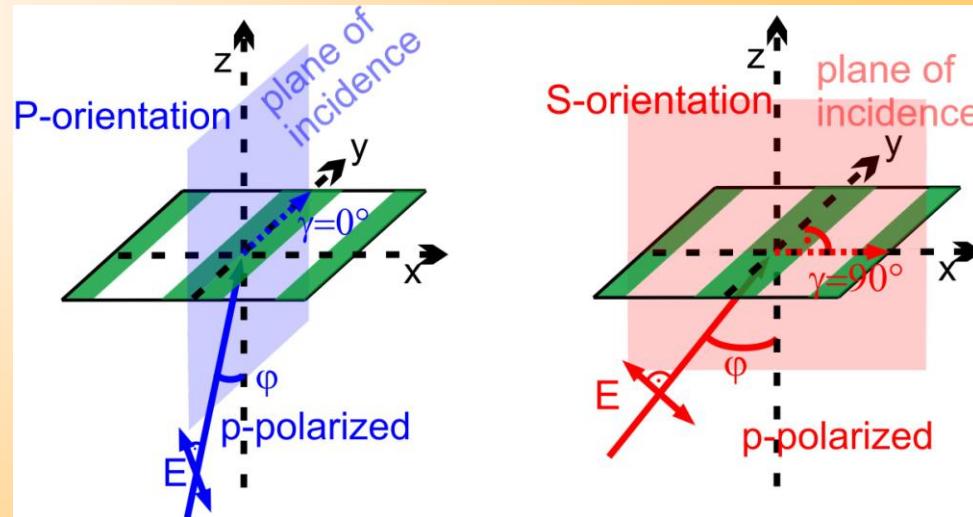
$$H_{z\_TM} = 0$$

## Components of $\mathbf{k}$ vector of oblique incident beam

$$k_x = k_0 \cdot \sin \varphi \cdot \sin \gamma$$

$$k_y = k_0 \cdot \sin \varphi \cdot \cos \gamma$$

$$k_z = k_0 \cdot \cos \varphi$$



## P/S-orientation:

- ◆ Intensity modulation along/perpendicular to NbN wires

## Media

- Cauchy formulas
  - ◆ Sapphire, NbNO<sub>x</sub>
- Tabulated datasets
  - ◆ Gold, NbN
    - ◆ M. A. Ordal, et al:  
*Appl. Opt.*, **22/7**, 1099-1119 (1983).

| Index of refraction | n1    | n2   |
|---------------------|-------|------|
| Sapphire            | 1.75  |      |
| NbNO <sub>x</sub>   | 2.28  |      |
| HSQ                 | 1.39  |      |
| Gold                | 0.559 | 9.81 |
| NbN                 | 5.23  | 5.82 |

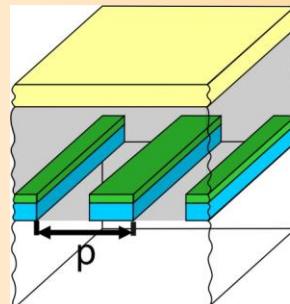
# Optical systems illuminated by p-polarized light

|  |                   |
|--|-------------------|
|  | Au                |
|  | HSQ               |
|  | NbN               |
|  | NbNO <sub>x</sub> |

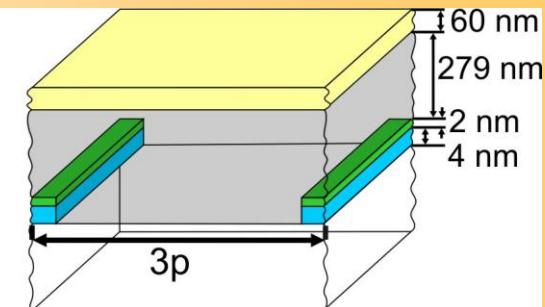
## ◆ OC-SNSPD

- ◆ 60 nm Au reflector on 279 nm HSQ

p=200/220/237 nm

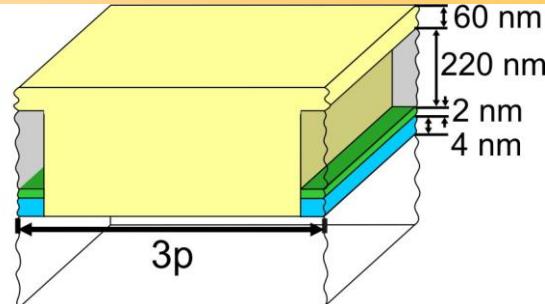
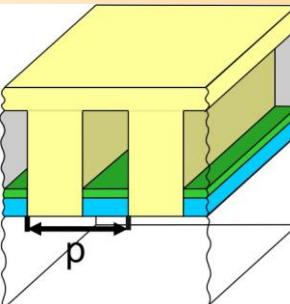
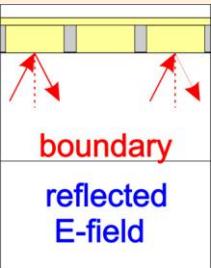


3p=600/660/710 nm



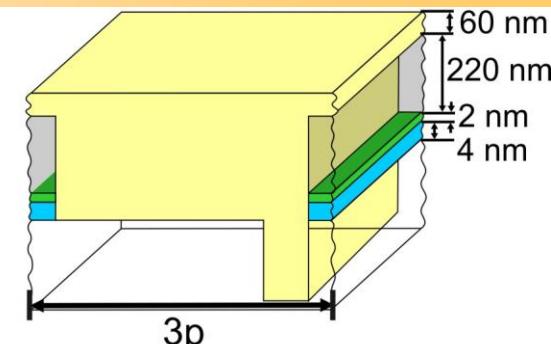
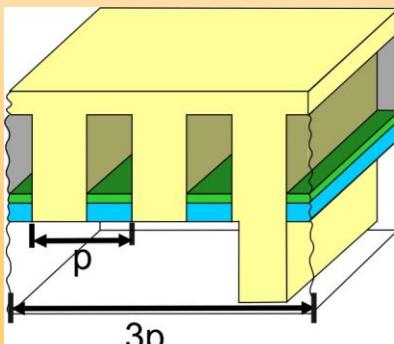
## ◆ NCAI-SNSPD

- ◆ 220 nm long nano-cavities closed by vertical, horizontal Au segments



## ◆ NCDAI-SNSPD

- ◆ longer vertical Au segments



## ◆ Parametric sweep

$$\varphi_{\text{sweep}}^{\text{entire}} = [0^\circ, 85^\circ]$$

$$\gamma_{\text{sweep}}^{\text{entire}} = [0^\circ, 90^\circ]$$

$$\Delta\varphi = \Delta\gamma = 5^\circ$$

$$\varphi_{\text{sweep}}^{\text{1D, low}} = [0^\circ, 90^\circ]$$

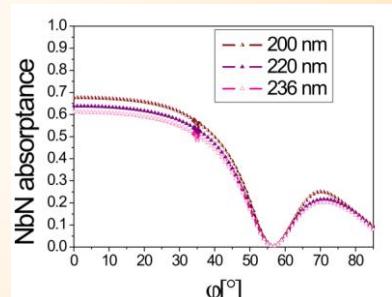
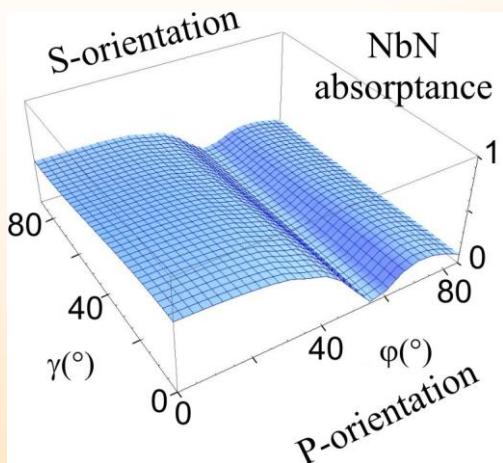
$$\Delta\varphi = 1^\circ$$

$\varphi_{\text{sweep}}^{\text{1D, high}}$  : around maxima

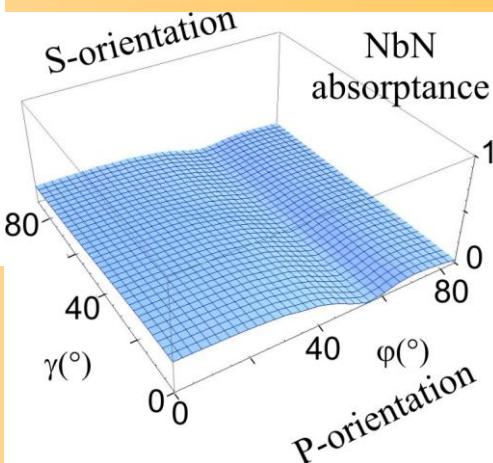
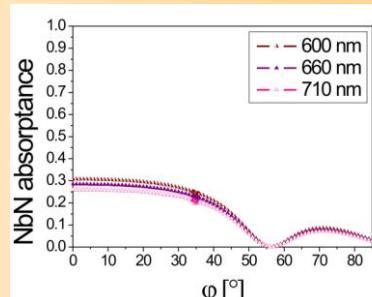
$$\Delta\varphi = 0.05^\circ$$

# Optical response in OC-SNSPDs

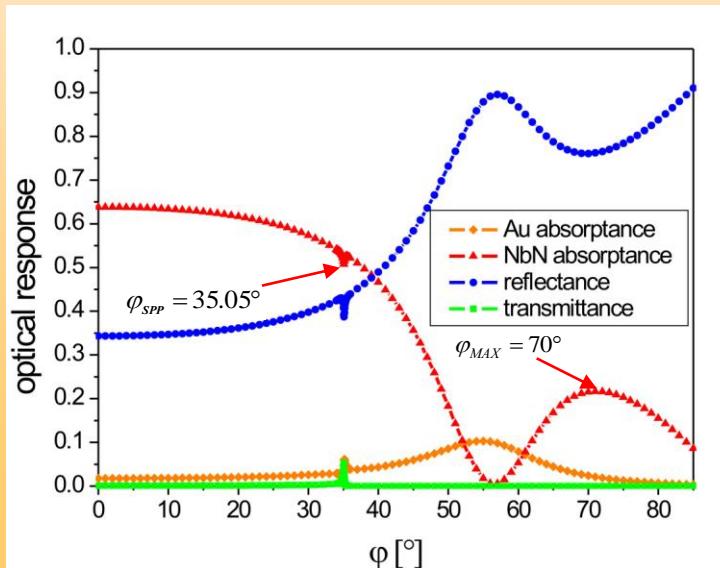
$p=200/220/237\text{ nm}$



$3p=600/660/710\text{ nm}$



- ◆ Larger absorptance in P-orientation
- ◆ E-field oscillation parallel to NbN wires
- ◆ perpendicular incidence in P-orientation

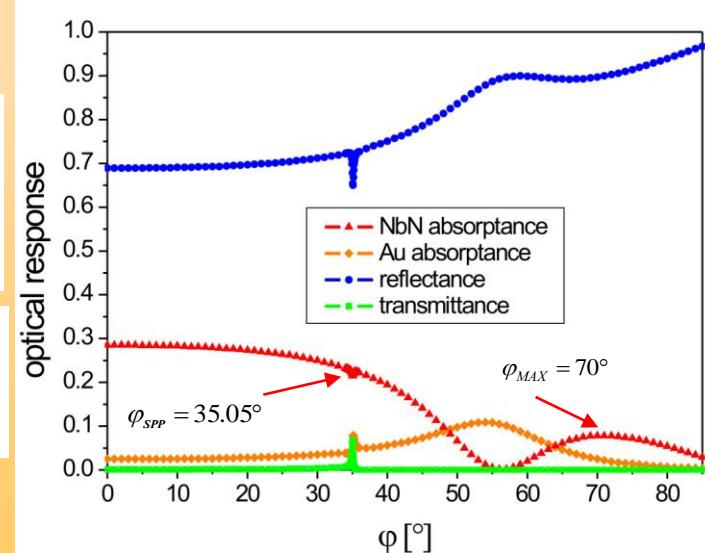


## ATIR characteristics

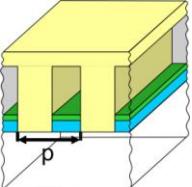
NbN absorptance  
<63.8 %, 28.5 %->  
global maximum at  $0^\circ$   
local maximum at ATIR

Au absorptance  
local maximum at  $35.15^\circ$   
global maximum at  $55^\circ$

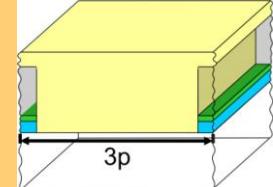
little near-field at TIR



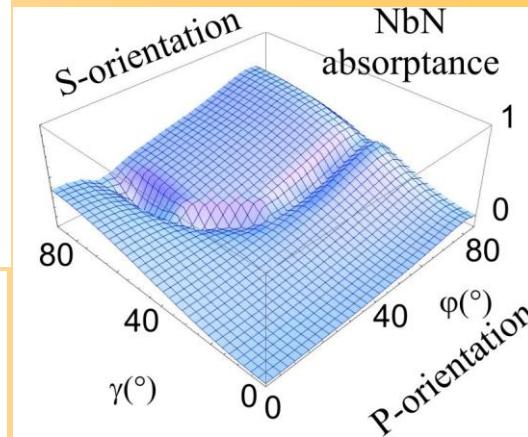
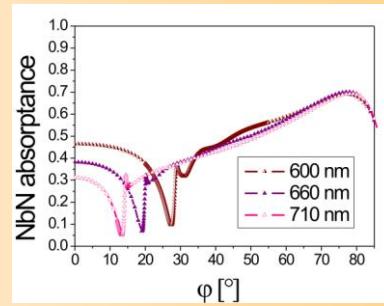
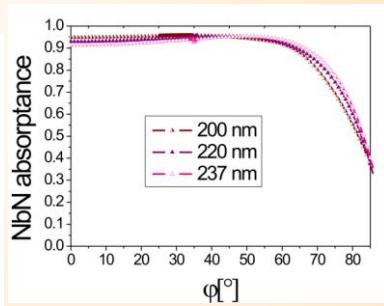
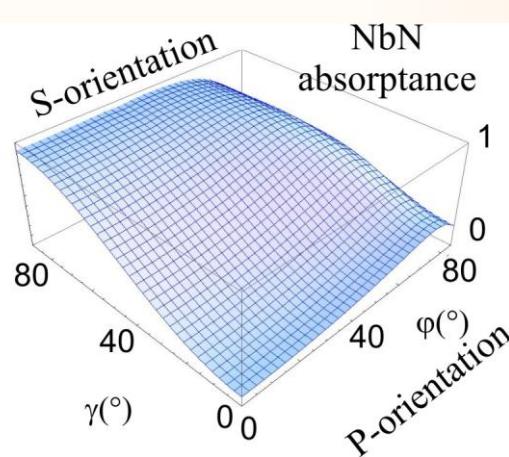
# Optical response in NCAI-SNSPDs



$p=200/220/237 \text{ nm}$

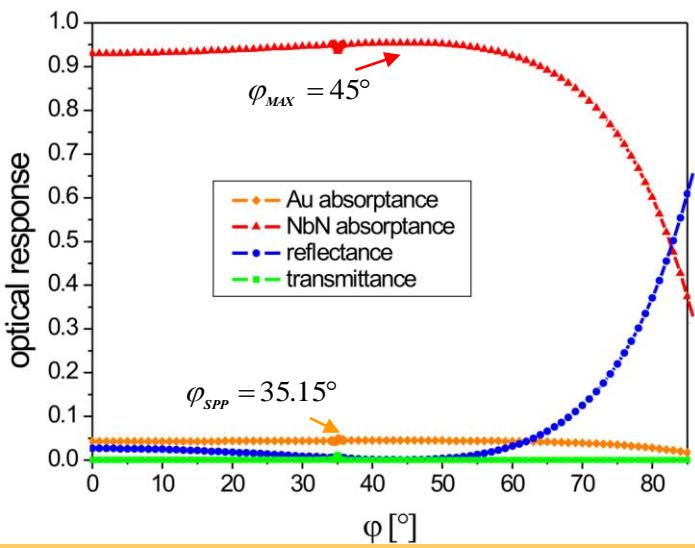


$3p=600/660/710 \text{ nm}$



- ◆ Larger absorptance in S-orientation
- ◆ E-field oscillation perpendicular to NbN wires
- ◆ perpendicular incidence in S-orientation

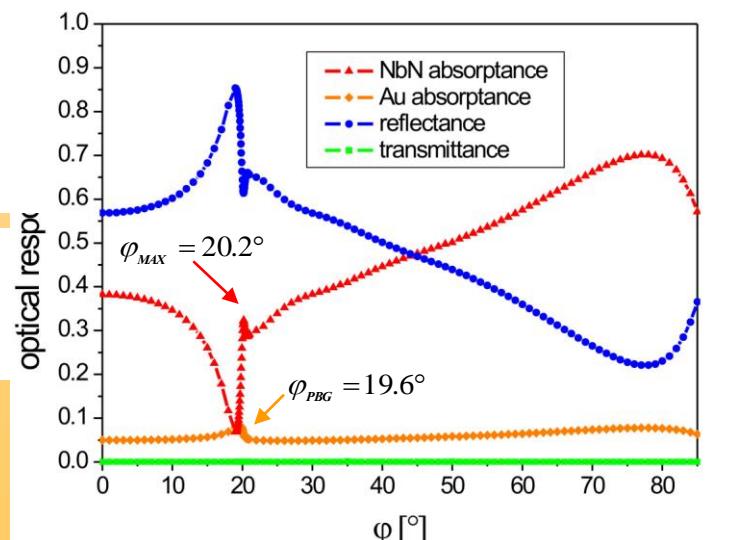
## Suppressed reflectance



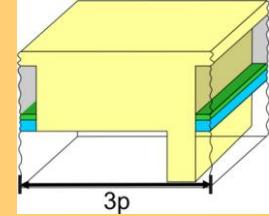
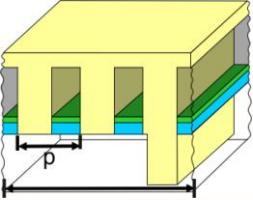
NbN absorptance  
 <-95.4%, 38.2% ->  
 <-global maximum at ATIR  
 local maximum (32.3%)  
 at PBG-edge->

Au absorptance  
 <-global maximum at SPP  
 global maximum at PBG->  
 <-little near-field at TIR  
 suppressed transmittance->

## ATIR characteristics

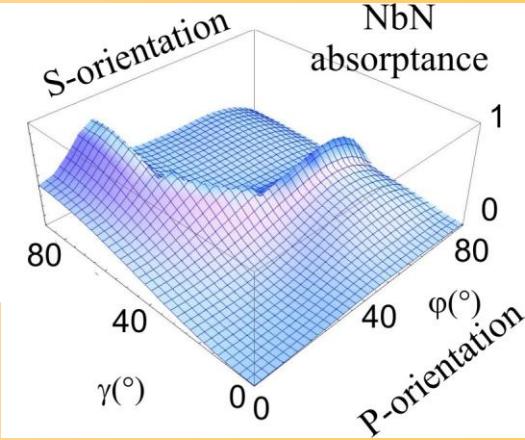
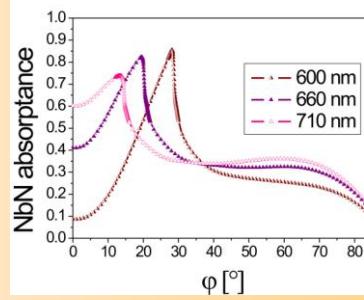
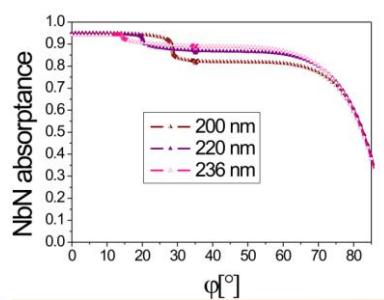
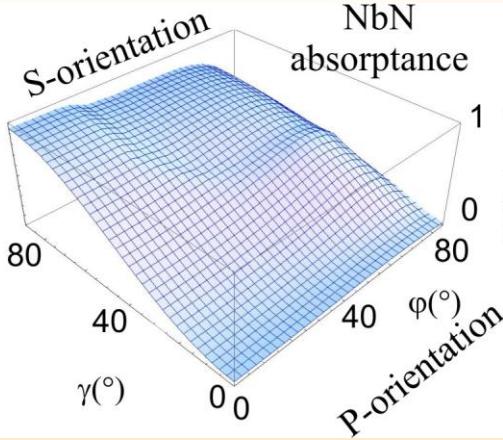


# Optical response in NCDAI-SNSPDs

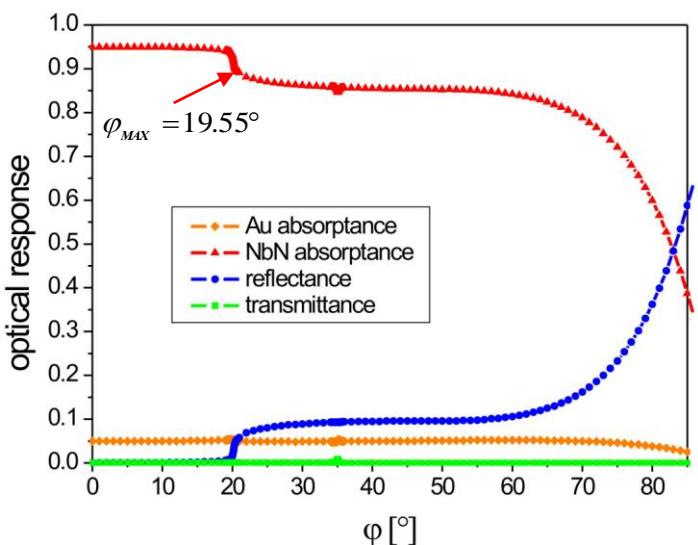


$p=200/220/237 \text{ nm}$

$3p=600/660/710 \text{ nm}$

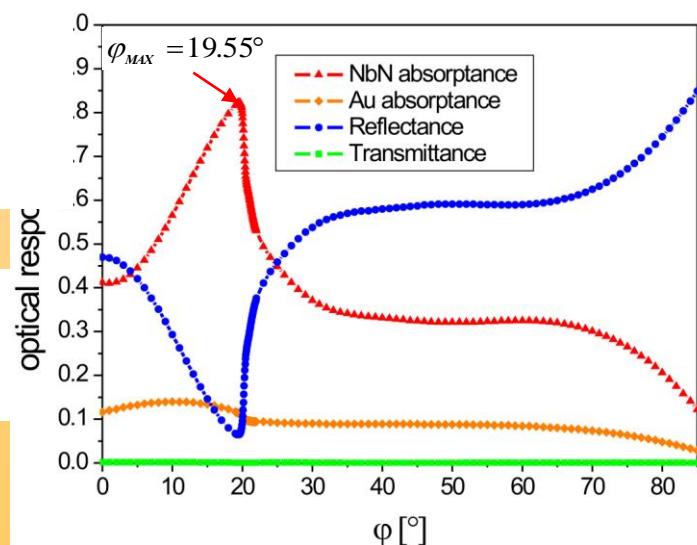


- ◆ Larger absorptance in S-orientation
- ◆ E-field oscillation perpendicular to NbN wires
- ◆  $p$ : perpendicular incidence in S-orientation
- ◆  $3p$ : tilting to Plasmonic-Band-Gap

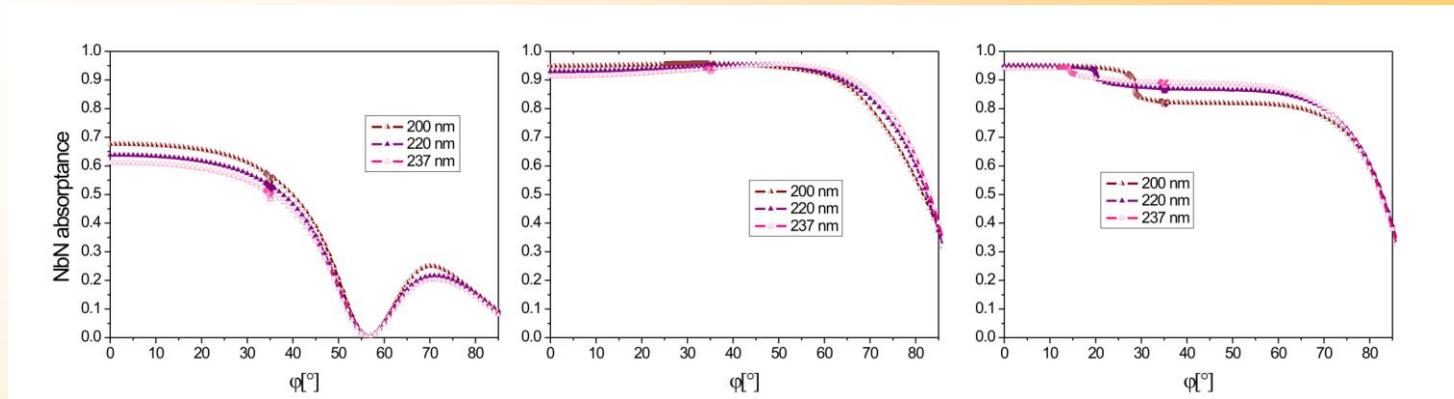


NbN absorptance  
<-94.9%  
global maximum at  $\phi=0^\circ$   
82.3%->  
global maximum at PBG

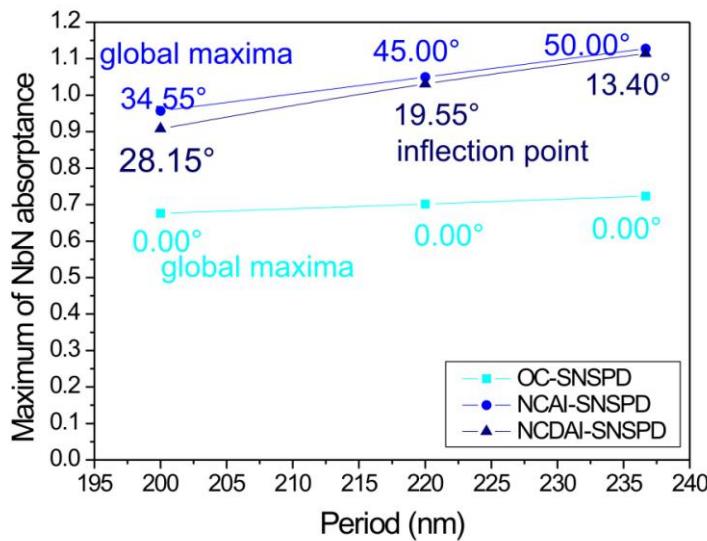
Au absorptance  
<-global maximum at SPP  
inflection at PBG->  
<-little near-field at TIR  
supressed transmittance->



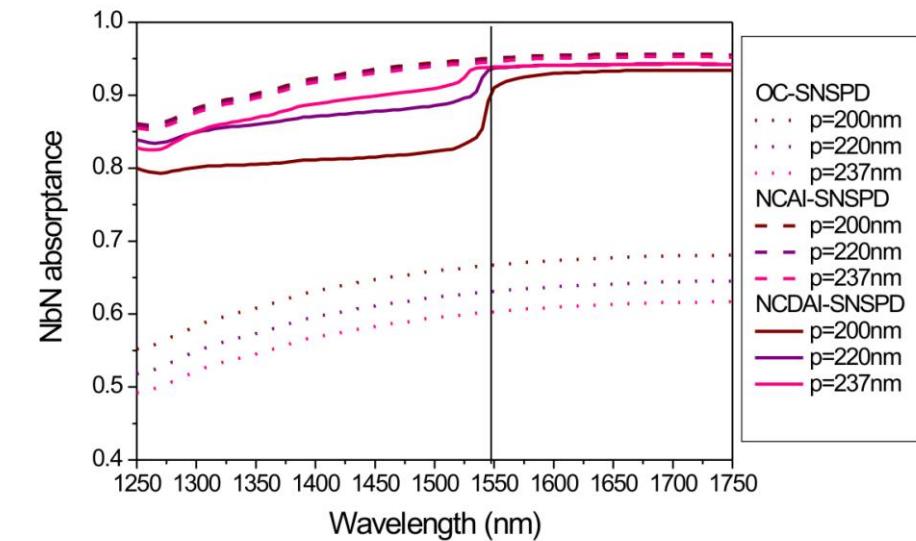
# Comparison of NbN absorptances in p-periodic designs



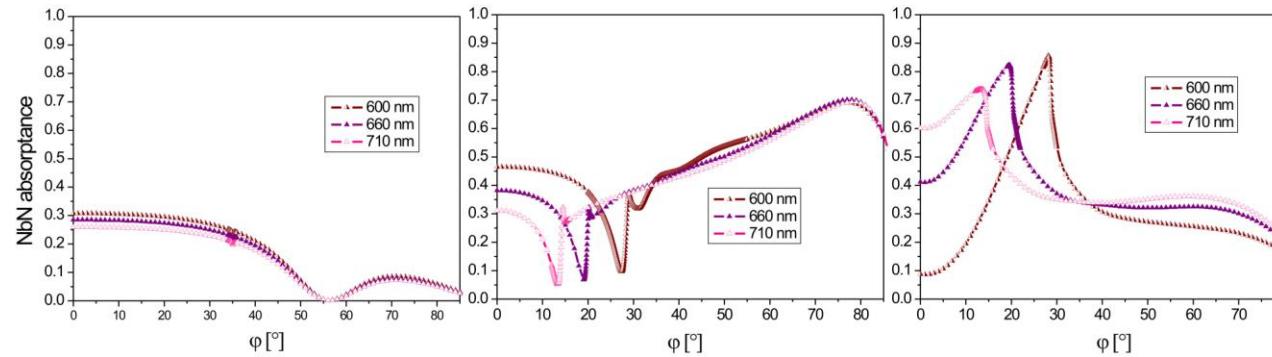
Largest slope of normalized NbN absorptance  
in NCDAI-SNSPDs



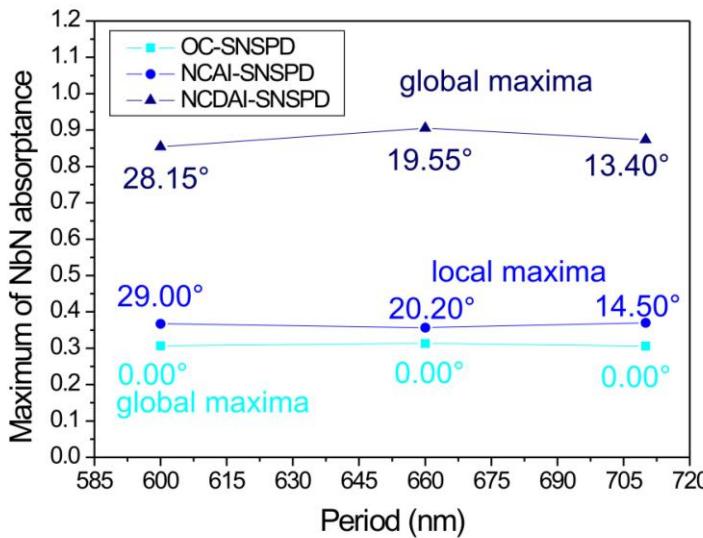
steep slope on NbN absorptance  
at 1550 nm in 220 nm design



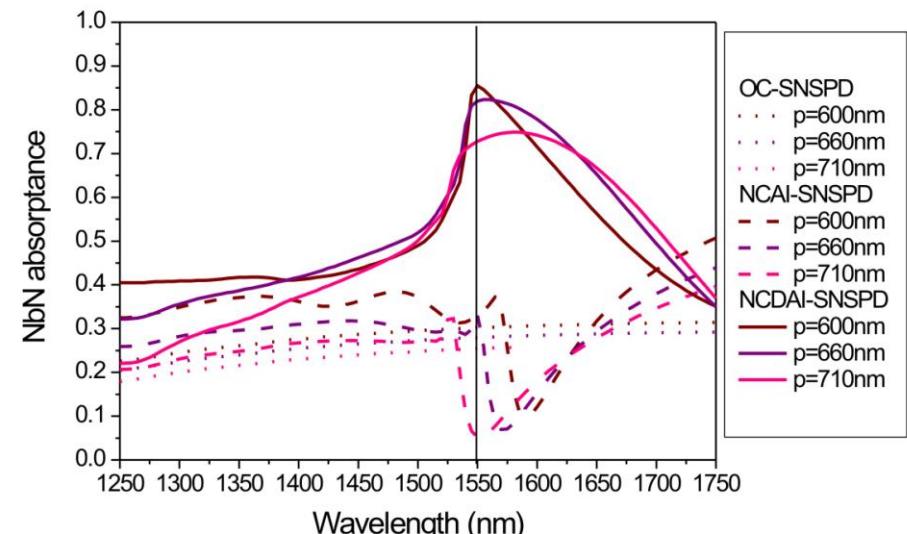
# Comparison of NbN absorptances in 3p-periodic designs



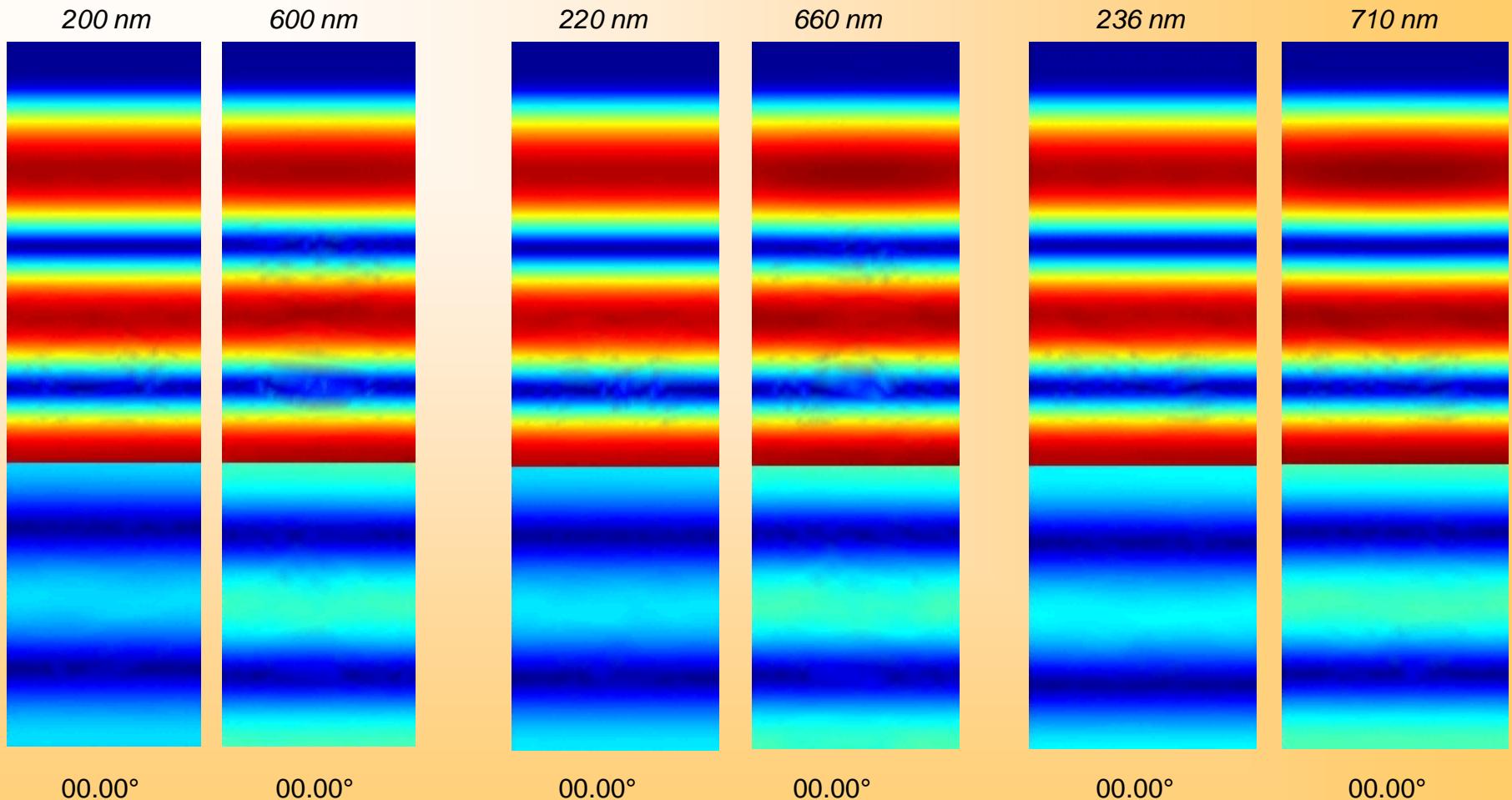
local maxima on normalized NbN absorptance at 660 nm  
in OC-SNSPD and NCDAI-SNSPDs



monotonous increase in OC-SNSPD  
local maxima at 1550 nm in 660 nm design in NCAI-SNSPD  
huge global maxima at 1550/**1561/1585** nm in NCDAI-SNSPDs

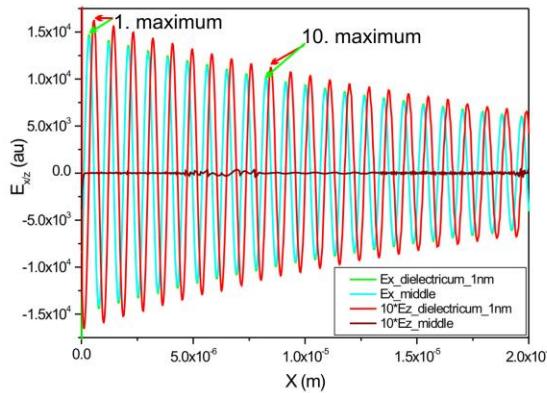
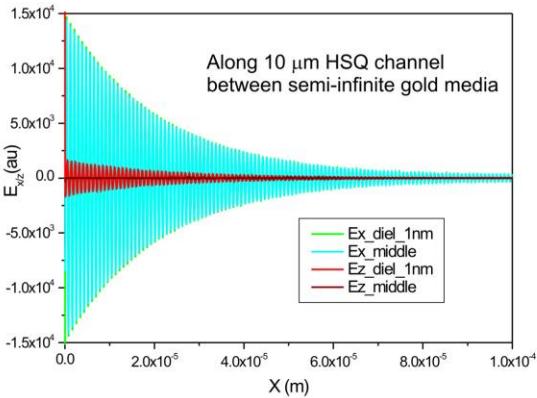


# Time evolution of the E-field in OC-SNSPDs



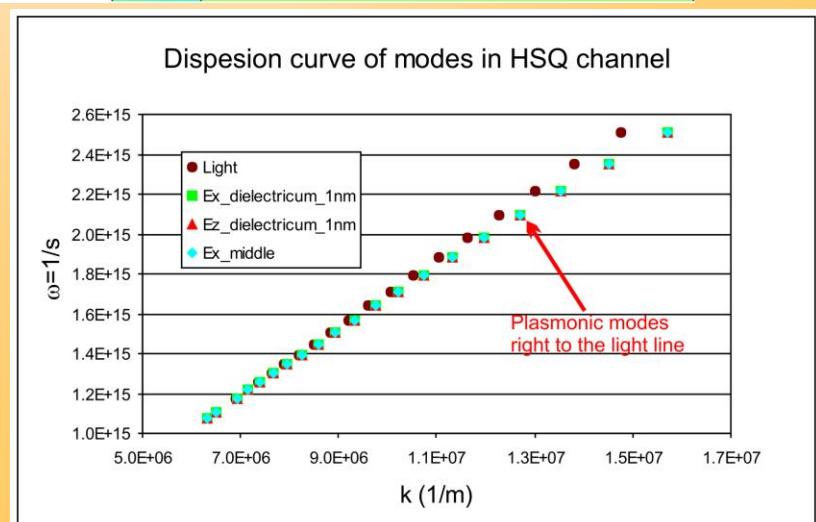
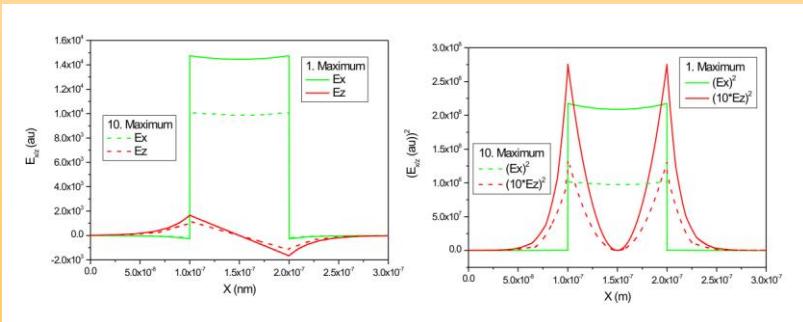
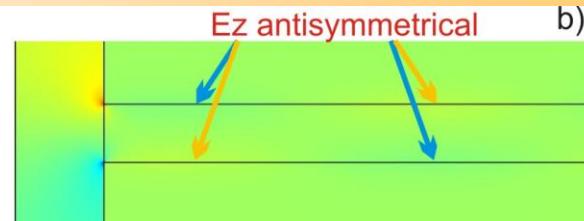
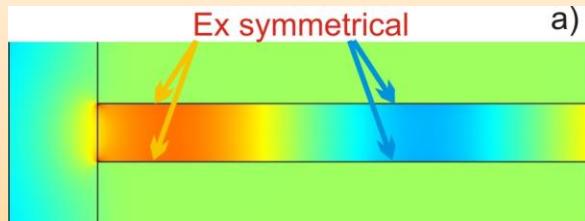
E-field antinode at sapphire-NbN interface

# Near-field explanation: plamonic modes in MIM channels



$$\omega_p^{Gold} = \sqrt{\frac{ne^2}{m\epsilon}} = 1.21479 \cdot 10^{17} \frac{1}{\text{s}}$$

$$\frac{E_{transversal}}{E_{longitudinal}} = \frac{E_x}{E_z} = \sqrt{\frac{\omega_p^2 - \omega^2}{\epsilon_1 \cdot \omega^2}} = 10.206$$



# Time evolution of the E-field in NCAI-SNSPDs

Maximal cavity filling: m=1, k=3,4,5

Enhancement  
at Au-air

200 nm

600 nm



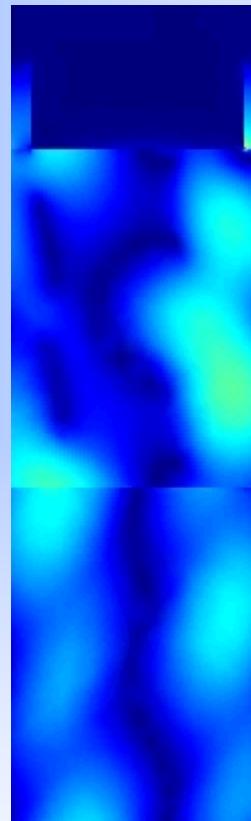
Supressed reflection in p-periodic designs

220 nm

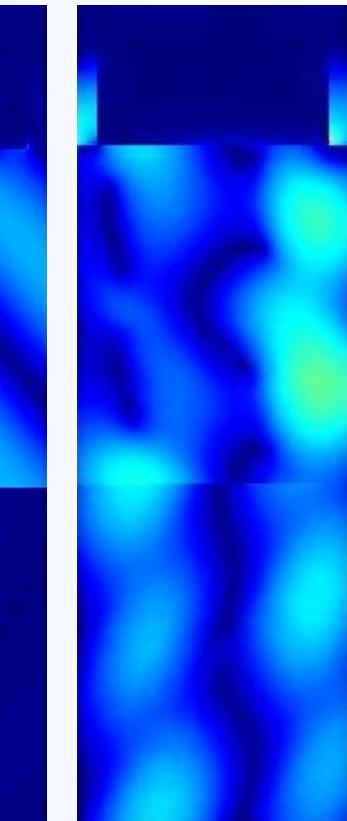
660 nm



236 nm



710 nm



34.55°

29.00°

45.00°

20.20°

50.00°

14.50°

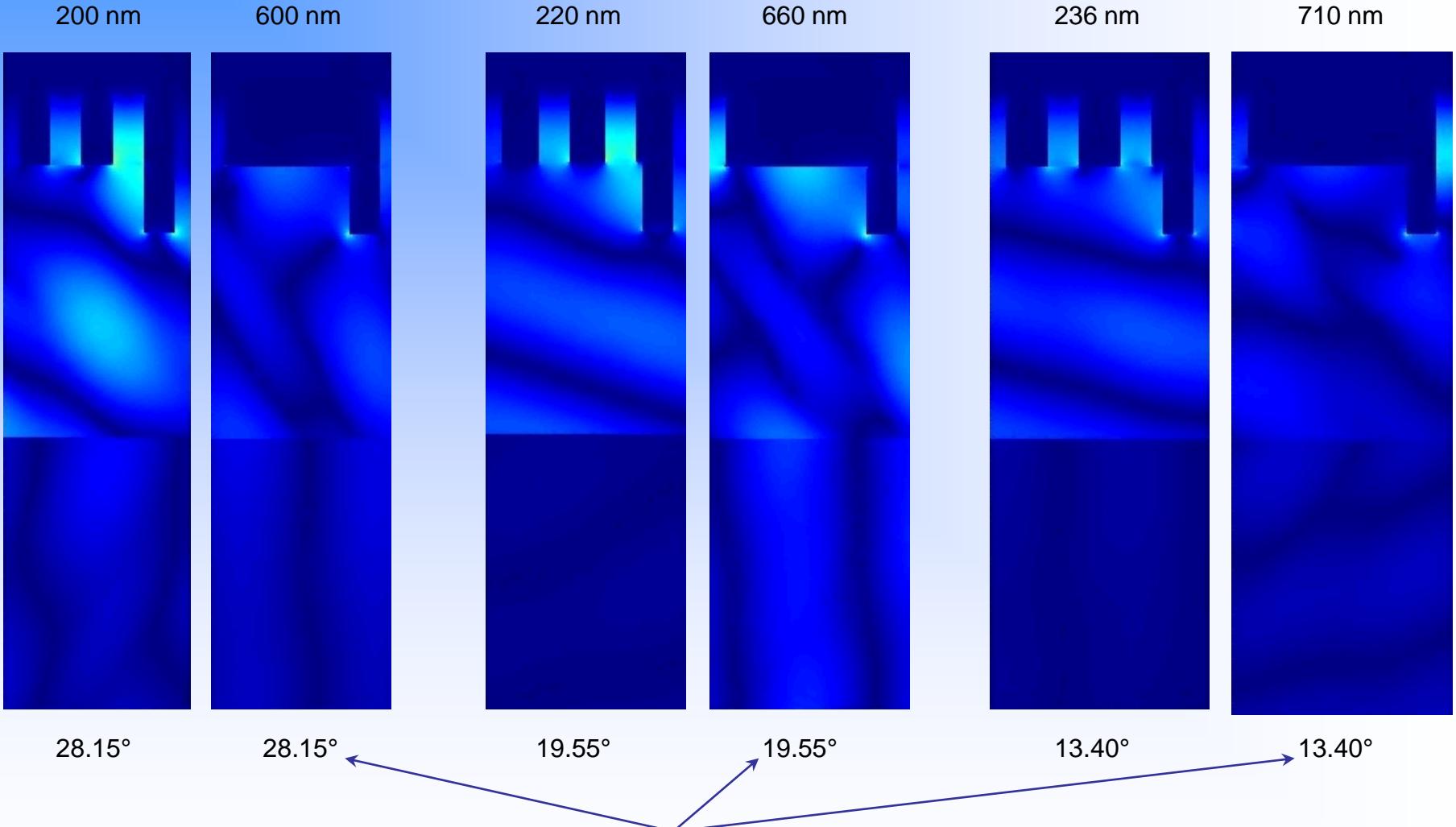
Backward propagating waves with wavelength (889nm) larger than  $\lambda/n$ :  
**Brewster waves** at PBG-edge

$$-\frac{2\pi}{\lambda_{\text{Brewster wave}}} = \frac{2\pi}{\lambda} \sin \varphi - \frac{2\pi}{3p}$$

$$\sin \varphi^{m,k} = \frac{n_{\text{sapphire}}}{kp}$$

## Time evolution of the E-field in NCDAI-SNSPDs

$$-\frac{2\pi}{\lambda_{SPP}} = \frac{2\pi}{\lambda} \sin \varphi - \frac{2\pi}{3p}$$



Backward propagating waves with wavelength (878 nm) corresponding to  $\lambda_{SPP}$ :  
**back-deflected plasmonic waves** at the middle of the PBG opening in p and 3p periodic designs

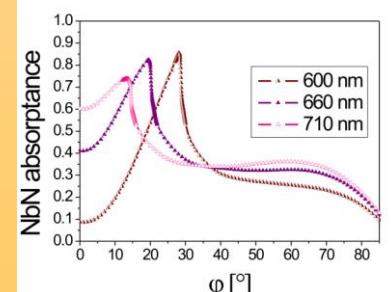
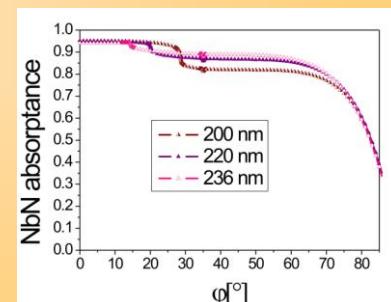
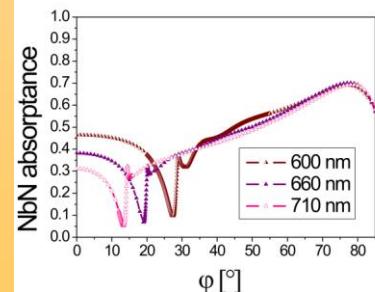
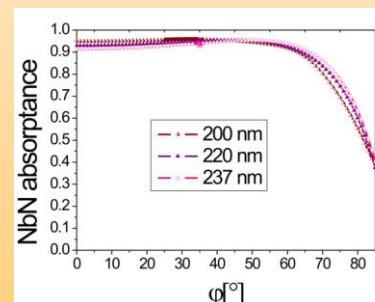
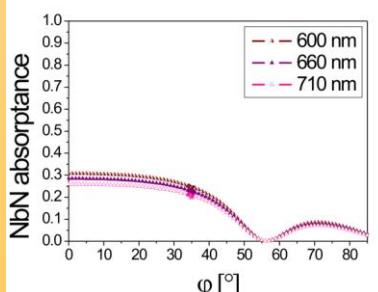
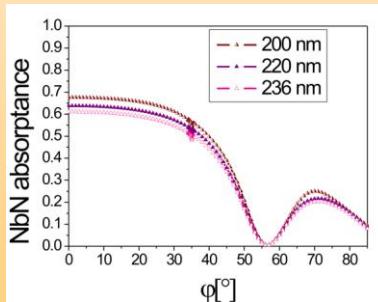
# Summary and outlook

## ➤ Photodetectors might be optimized via plasmonic structures

- ◆ synchronous polar-azimuthal orientation to optimize the near-field distribution and to maximize the absorptance
- ◆ Each device has optimal polar-azimuthal orientation

## ➤ SNSPD

- ◆ OC: cavity-resonant mode
- ◆ NCAI:
  - ◆ coupled resonances on p-periodic NCA,
  - ◆ coupling prohibited via propagating waves on 3p-periodic NCA,
- ◆ NCDAI
  - ◆ Highest efficiency via coupled localized and propagating modes



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